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APPLICATION NO	FILINO DATE	EJRNI NAMED INVENTOR	ATTORNEY DOCKET NO	CONFIRMATION NO
(19.73 <i>K</i> ₂ ()43	12/12/2000	Yue Kao	917575 0414 (TAMUS 1529)	7225
	590 (02.21.2002) - L. D.			
Baker Botts L.L.P. 2001 Ross Avenue			EXAMINER	
Dallas, TX 75201-2980			COLEMAN, WILLIAM D	
			ARTUNII	PAPER NUMBER
			2823	
			DATE MAILED: 02/21/2002	

Please find below and or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)
	09/736,043	KUO, YUE
Office Action Summary	Examiner	Art Unit
	W. David Coleman	2823
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet	with the correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1 1 after SIX (6) MONTHS from the mailing date of this communication if the period for reply specified above is less than thirty (30) days, a replicit NO period for reply is specified above the maximum statutory period via Failure to reply within the set or extended period for reply will by statute. Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1 704(b)	36(a) In no event, however, may y within the statutory minimum of the will apply and will expire SIX (6) MC cause the application to become	a reply be timely filed nirty (30) days will be considered timely DNTHS from the mailing date of this communication. ABANDONED (35 U.S.C. & 133)
Status	2 / 222	
1) Responsive to communication(s) filed on <u>12 L</u>		
_	is action is non-final.	
3) Since this application is in condition for allows closed in accordance with the practice under	ance except for formal m <i>Ex parte Quayle</i> , 1935 C	atters, prosecution as to the merits is C.D. 11, 453 O.G. 213.
Disposition of Claims		
4) Claim(s) 1-30 is/are pending in the application		
4a) Of the above claim(s) is/are withdraw	vn from consideration.	
5) Claim(s) is/are allowed		
6)⊡ Claim(s) <u>1-30</u> is/are rejected.		
7) Claim(s) <u>14</u> is/are objected to.		
8) Claim(s) are subject to restriction and/or	r election requirement.	
Application Papers		
9)☐ The specification is objected to by the Examine	۲.	
10)⊡ The drawing(s) filed on <u>12 December 2000</u> is/ar	e: a)⊠ accepted or b)□	objected to by the Examiner.
Applicant may not request that any objection to the	e drawing(s) be held in abe	yance. See 37 CFR 1.85(a).
11) The proposed drawing correction filed on	is: a) ☐ approved b) ☐	disapproved by the Examiner.
If approved, corrected drawings are required in rep	ly to this Office action.	
12) The oath or declaration is objected to by the Exa	aminer.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C.	§ 119(a)-(d) or (f).
a)⊠ All_b)□ Some * c)□ None of:		
1. Certified copies of the priority documents	s have been received.	
2. Certified copies of the priority documents	have been received in ,	Application No
3. Copies of the certified copies of the prior application from the International Bur * See the attached detailed Office action for a list of the control of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the certified copies of the prior application for a list of the prior application from the list of the list of the prior application from the list of	eau (PCT Rule 17.2(a)).	ŭ
14) Acknowledgment is made of a claim for domestic	•	
a) The translation of the foreign language pro		- , , , , , , , , , , , , , , , , , , ,
15) Acknowledgment is made of a claim for domesting		
attachment(s)		
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of	Summary (PTO-413) Paper No(s) Informal Patent Application (PTO-152)
Patent and Trademark Office O-326 (Rev. 04-01) Office Act	tion Summan	D (D . N . 2

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States

- 2. Claims 1, 2, 3, 4, 7, 8, 9, 10, 11 and 18 are rejected under 35 U.S.C. 102(b) as being anticipated by Gardner et al., U.S. Patent 5,350,484.
- 3. Pertaining to claims 1, 11 and 18, <u>Gardner</u> discloses a semiconductor process as claimed. See **FIGS**. **2A-2C**, where <u>Gardner</u> teaches a method for forming a conductive pattern for a semiconductor device comprising:

patterning a mask layer 4 outwardly from a conductive layer 3 of the semiconductor device, the patterning defining portions 6 of the conductive layer 3 where vias through the conductive layer 3 are desired;

exposing the semiconductor device to a plasma 10, the plasma converting the unmasked portions of the conductive layer 3 into a compound 8: and

exposing the semiconductor device to a treatment process, the treatment process selectively removing the compound (column 8, lines 22-27).

4. Pertaining to claims 2 and 28, <u>Gardner</u> teaches wherein the conductive layer **3** comprises a copper material (column 6, lines 55-56).

Pertaining to claim 3. Gardner teaches removing the mask layer 4 from the semiconductor device

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5. Pertaining to claims 4 and 20. <u>Gardner</u> teaches removing the mask layer 4 after removing the compound 8

- 6. Pertaining to claims 7 and 15, <u>Gardner</u> teaches providing a barrier layer **2** between the conductive material **3** and the substrate (not numbered).
- 7. Pertaining to claims 8 and 14, <u>Gardner</u> teaches wherein the conductive material 3 comprises a copper material, and wherein exposing the semiconductor device to a plasma 10 comprises exposing the semiconductor device to a chlorine-containing gas (column 7, line 26).
- 8. Pertaining to claims 9, 23, 24, 25, 26, 29 and 30, <u>Gardner</u> teaches wherein the compound comprise a copper chloride material **8**, and wherein exposing the semiconductor device to a treatment process comprises exposing the semiconductor device to a hydrogen chloride solution to remove the copper chloride material (See table III).
- 9. Pertaining to claims 10, 17 and 19, <u>Gardner</u> teaches wherein the mask layer comprises a photoresist material 5.
- 10. Pertaining to claim 13, <u>Gardner</u> teaches wherein forming a conductive layer 3 comprises forming a copper layer outwardly from the substrate.
- 11. Pertaining to claims 16, 22 and 27, <u>Gardner</u> teaches wherein exposing the electronic device to a plasma comprises controlling the exposure of the electronic device to the plasma 10 to form a substantially perpendicular interface between the masked conductive material 3 and the compound 8.

Claim Rejections - 35 USC § 103

12. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- 13. Claims 5, 12 and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al., U.S. Patent 5,350,484 as applied to claims 1-4, 7-11, 13-20 and 22-30 above.
- 14. <u>Gardner</u> teaches a semiconductor process substantially as claimed, however, <u>Gardner</u> fails to teach the selection of removing the masking layers before removing the compound. Applicant is reminded that selection of any order of performing process steps is prima facie obvious in the absence of new or unexpected results. In re Burhans, 154 F.2d 690, 69 USPQ 330 (CCPA 1946). However, in the absence of new or unexpected results, the mere reversal of the order of performing process steps has been held to be prima facie obvious. In re Burhans, 154 F.2d 690, 69 USPQ 330 (CCPA 1946).
- 15. Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al., U.S. Patent 5,350,484 as applied to claims 1-4, 7-11, 13-20 and 22-30 above, and further in view of Ye et al., U.S. Patent 6,010,603.
- 16. Gardner discloses a semiconductor process substantially as claimed as discussed above. However, Gardner fails to teach wherein exposing the semiconductor device to a treatment process comprising: exposing the semiconductor device to a substantially inert atmosphere; and heating the semiconductor device to between 300 and 800 degrees Celsius to remove the compound. Ye teaches exposing the semiconductor device to a substantially inert atmosphere and heating the semiconductor device within the range as claimed to remove the compound. See column 13, lines 50-60, where Ye teaches the gas feed rates to the etch chamber were 140 secm of argon, 15 secm of chlorine, and 5 secm of N₂. The preferred substrate temperature is

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preferably less than about 350° C. In view of <u>Ye</u>, it would have been obvious to one of ordinary skill in the art to incorporate the compound removal process of <u>Ye</u> into the <u>Gardner</u> semiconductor process because it helps volatilize some species such as CuCl_x, enabling these species to leave the film surface (column 13, lines 60-62).

Specification

17. Claim 14 is objected to because of the following informalities: the term "exposing the electronic device to a plasma appears twice in the same sentence. Appropriate correction is required.

Conclusion

18. Any inquiry concerning this communication or earlier communications from the examiner should be directed to W. David Coleman whose telephone number is 703-305-0004. The examiner can normally be reached on 9:00 AM-5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on 703-308-4918. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7721 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

W. David Coleman Examiner Art Unit 2823

WDC February 16, 2002

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